

FDN361BN

30V N-Channel, Logic Level, PowerTrench[®] MOSFET

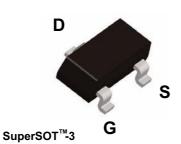
General Description

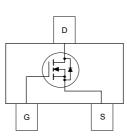
These N-Channel Logic Level MOSFETs are produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance.

These devices are particularly suited for low voltage applications in notebook computers, portable phones, PCMCIA cards, and other battery powered circuits where fast switching, and low in-line power loss are needed in a very small outline surface mount package.

Features

- 1.4 A, 30 V. $R_{DS(ON)} = 110 \text{ m}\Omega @ V_{GS} = 10 \text{ V}$ $R_{DS(ON)} = 160 \text{ m}\Omega @ V_{GS} = 4.5 \text{ V}$
- Low gate charge
- Industry standard outline SOT-23 surface mount package using proprietary SuperSOT[™]-3 design for superior thermal and electrical capabilities
- High performance trench technology for extremely low R_{DS(ON)}





Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol		Parameter	Ratings	Units	
V _{DSS}	Drain-Sourc	e Voltage	30	V	
V _{GSS}	Gate-Source	e Voltage		± 20	V
I _D	Drain Curre	nt – Continuous	(Note 1a)	1.4	Α
		– Pulsed		10	
PD	Power Dissi	pation for Single Operation	(Note 1a)	0.5	W
			(Note 1b)	0.46	
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C
Therma	I Charact	teristics			
$R_{\theta JA}$	Thermal Re	mal Resistance, Junction-to-Ambient (Note 1a)		250	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case (Note 1)		(Note 1)	75	
Packag	e Markin	g and Ordering Ir	nformation		
Device Marking		Device	Reel Size	Tape width	Quantity
361B		FDN361BN	7"	8mm	3000 units

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Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	racteristics					
BV _{DSS}	Drain–Source Breakdown Voltage	V _{GS} = 0 V, I _D = 250 μA	30		1	V
ΔBV _{DSS} ΔT _J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A,Referenced to 25°C		26		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24 V$, $V_{GS} = 0 V$			1	μA
		V _{DS} = 24 V, V _{GS} = 0 V, T _J = 55°C			10	μA
I _{GSS}	Gate–Body Leakage	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	1	2.1	3	V
R _{DS(on)}	Static Drain–Source On–Resistance	$ \begin{array}{l} V_{GS} = 10 \ V, \qquad I_D = 1.4 \ A \\ V_{GS} = 4.5 \ V, \qquad I_D = 1.2 \ A \\ V_{GS} = 10 \ V, \ I_D = 1.4 \ A, \ T_J = 125^\circ C \end{array} $		92 120 114	110 160 150	mΩ
I _{D(on)}	On–State Drain Current	$V_{GS} = 4.5 V, V_{DS} = 5 V$	3.5		100	Α
g _{FS}	Forward Transconductance	$V_{\rm DS} = 5 \text{ V}, \qquad I_{\rm D} = 1.4 \text{ A}$		4		S
-	c Characteristics					
C _{iss}	Input Capacitance $V_{ns} = 15 V$, $V_{Gs} = 0 V$,			145	193	pF
C _{oss}	Output Capacitance	f = 1.0 MHz		35	47	pF
Crss	Reverse Transfer Capacitance			15	23	pF
R _G	Gate Resistance	V_{GS} = 15 mV, f = 1.0 MHz		1.6		Ω
Switchin	ng Characteristics (Note 2)		I			L
t _{d(on)}	Turn–On Delay Time	V _{DD} = 15 V, I _D = 1 A,	l	3	6	ns
tr	Turn–On Rise Time	$V_{GS} = 10 \text{ V}, \qquad R_{GEN} = 6 \Omega$		8	16	ns
t _{d(off)}	Turn–Off Delay Time	1		16	29	ns
t _f	Turn–Off Fall Time			2	4	ns
Qg	Total Gate Charge	$V_{DS} = 15 V$, $I_D = 1.4 A$,		1.3	1.8	nC
Q _{gs}	Gate–Source Charge	V _{GS} = 4.5 V		0.5	1	nC
Q _{gd}	Gate–Drain Charge			0.5		nC
Drain-S	ource Diode Characteristics					
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$, $I_S = 0.42 A$ (Note 2)		0.8	1.2	V
t _{rr}	Diode Reverse Recovery Time	$I_F = 1.4 \text{ A}, \qquad d_{iF}/d_t = 100 \text{ A}/\mu \text{s}$		11	22	nS
Q _{rr}	Diode Reverse Recovery Charge	7		4	1	nC

Notes:

R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design while R_{0CA} is determined by the user's board design.

a) 250°C/W when mounted on a 0.02 in² pad of 2 oz. copper.



b) 270°C/W when mounted on a minimum pad.

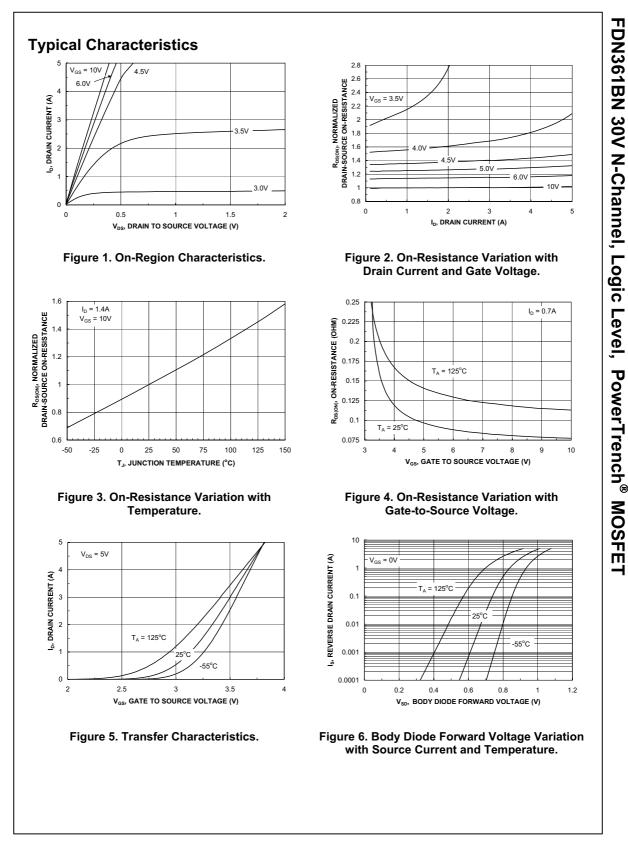
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6 Scale 1 : 1 on letter size paper

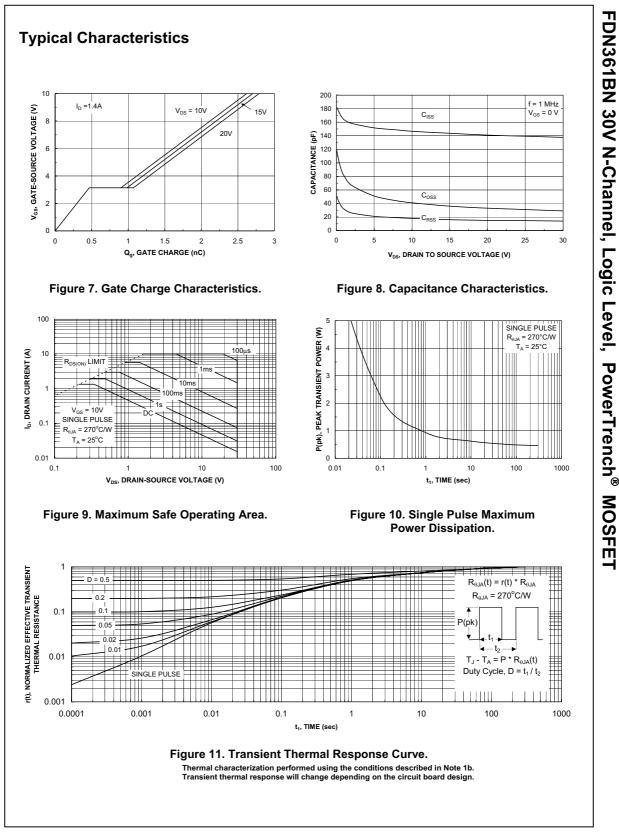
2. Pulse Test: Pulse Width \leq 300 $\mu s,$ Duty Cycle $\leq 2.0\%$

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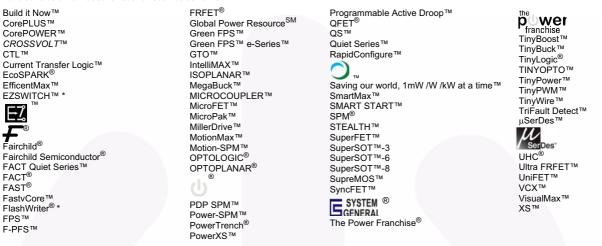
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